## NSN 5961-01-087-7225

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-087-7225 **Inclosure Material:** Metal all transistor **Overall Length:** 1.563 inches all transistor **Overall Height:** 1.050 inches all transistor **Mounting Facility Quantity:** 2 all transistor **Internal Configuration:** Junction contact-darlington connected all transistor **Electrode Internally-electrically Connected To Case:** Collector all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 4 transistor **Mounting Method:** Unthreaded hole all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 650.0 collector to base voltage, dc all transistor and 400.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 10.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 1 case all transistor and 2 pin all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Fiig: A110a0

No